Amendments to the Claims:

This listing of claims will replace all prior versions, and listings, of claims in the application:

Listing of Claims:

1. (Currently Amended) A carbon-containing component comprising a protective coating, wherein the carbon-containing component includes is selected from the group consisting of graphite, amorphous carbon, carbon fibers, and carbon-carbon composites, or a combination thereof; and

wherein the protective coating comprises a material selected from the group consisting of:

non-stoichiometric compounds of silicon and carbon; compounds of silicon, oxygen, and carbon; compounds of silicon, oxygen and nitrogen; compounds of silicon, nitrogen, and carbon; compounds of silicon, oxygen, nitrogen, and carbon; and silicon.

5

10

2-4. (Cancelled)

5. (Original) The carbon-containing component of claim 1, wherein said protective coating has a coefficient of thermal expansion which is less than the coefficient of thermal expansion of silicon carbide (SiC).

6-9. (Cancelled)

10. (Original) The carbon-containing component of claim 1, wherein carbon-containing component comprises a plate-fin heat exchanger.

5

10

15

5

11. (Original) The carbon-containing component of claim 1 wherein said protective coating has a graded composition through its thickness.

12. (Cancelled)

13. (Currently amended) A carbon-containing component comprising a protective coating, wherein the carbon-containing component includes is selected from the group consisting of graphite, amorphous carbon, carbon fibers, and carbon-carbon composites, or a combination thereof; and

wherein the protective coating comprises a material selected from the group consisting of:

silicon (Si); silicon carbide (SiC_y); silicon oxycarbide (SiO_xC_y); silicon oxynitride (SiO_xN_z); silicon carbonitride (SiC_yN_z); and

wherein x < 2, y < 1 and z < 4/3, and at least one of x, y, and z is greater than zero, and wherein the coefficient of thermal expansion of said protective coating is less than the coefficient of thermal expansion of silicon carbide (SiC).

silicon oxycarbonitride ($SiO_xC_yN_z$);

14-21. (Cancelled)

22. (Currently Amended) A carbon-containing component comprising a protective coating, wherein the carbon-containing component includes is selected from the group consisting of graphite, amorphous carbon, carbon fibers, and carbon-carbon composites, or a combination thereof; and wherein said protective coating comprises at least one material selected from the group consisting of:

non-stoichiometric compounds of silicon and carbon; non-stoichiometric compounds of silicon and oxygen; non-stoichiometric compounds of silicon and nitrogen; compounds of silicon, oxygen, and carbon; compounds of silicon, oxygen, and nitrogen; compounds of silicon, nitrogen, and carbon; compounds of silicon, oxygen, nitrogen, and carbon; and silicon.

- 23. (Previously presented) The carbon-containing component of claim 22, wherein said protective coating comprises at least two layers, wherein each of said layers comprises a material selected from said group.
- 24. (Previously presented) The carbon-containing component of claim 23, wherein each of said layers comprises a compound selected from the group consisting of silicon carbide (SiC_y); silicon oxycarbide (SiO_xC_y); silicon carbonitride (SiC_yN_z); and silicon oxycarbonitride (SiO_xC_yN_z), wherein x < 2, y < 1 and z < 4/3, and at least one of x, y, and z is greater than zero.
- 25. (Previously presented) The carbon-containing component of claim 24, wherein at least a portion of the carbon (C) in said compound of said layers is chemically bound.
- 26. (Previously presented) The carbon-containing component of claim 22, wherein said carbon-containing component comprises a plate-fin heat exchanger.

10

- 27. (Previously presented) The carbon-containing component of claim 22, wherein said protective coating is applied directly to a surface of said carbon-containing component.
- 28. (Original) The carbon-containing component of claim 22, wherein said protective coating has a coefficient of thermal expansion which is less than the coefficient of thermal expansion of silicon carbide (SiC).